The Limits of Beam Brightness from Photocathode RF Guns

D. H. Dowell In collaboration with SLAC and LBNL

32nd International Free-Electron Laser Conference Hilton Malmö City, Sweden, Aug. 23-27, 2010

•QE and the intrinsic cathode emittance
•Space charge emittance near the cathode
•RF contribution to the projected emittance
•Chromatic emittance of the gun solenoid
•Aberrations and field errors of the solenoid
•Summary and conclusions

Photoemission Theory for Metal Cathodes

In this theory the QE and intrinsic emittance are connected by the excess energy: the difference between the photon energy and the work function. The greater the excess energy the greater the QE and the higher the intrinsic emittance. This is also the case for prompt emitting semi-conductor cathodes such as Cs₂Te and SbK₂Cs. However slow emitters such as GaAs can have high QE and low emittance.



D.H. Dowell & J.F. Schmerge, PRST-AB 12,074201(2009)

Comparison of QE with Thermal Emittance Using a Consistent Theory for Metal Cathodes



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Comparison of Expt. and Theory for the Intrinsic Emittance



FIG. 4 (color online). Normalized projected emittance versus laser spot size for 3 different wavelengths on copper. (Q < 1 pC; solenoid scan method, Cu inset). Theory corresponds to Eq. (1) assuming $\Phi_{Cu} = 4.3 \text{ eV}$ (thermal effects not included).

261nm :
$$\phi_{eff}$$
 = 4.58 eV : ε_n / σ_x = 0.33 vs. 0.68expt.
272nm : ϕ_{eff} = 4.44 eV : ε_n / σ_x = 0.28 vs. 0.54expt.
282nm : ϕ_{eff} = 4.30 eV : ε_n / σ_x = 0.25 vs. 0.41expt.

Expt.-to-theory is ~2, consistent with other experiments



4.2

Effective Work Function (eV)

 10^{-7}

4 4.8

4.6

Thermal Emittance and Response Time of GaAs Lowest Intrinsic(Thermal) Emittance Response time and emittance depend upon photon wavelength

Due to electron-phonon scattering the delayed-emission electrons can reach thermal equilibrium with the lattice, giving the intrinsic emittance of GaAs a thermal-like emission component (given by kT) as well as prompt emission(given by the excess

energy) part.

$$\frac{\mathcal{E}_{GaAs,n}}{\sigma_{a}} = A_{slow} \sqrt{\frac{k_B T}{mc^2}} + A_{fast} \sqrt{\frac{\hbar\omega - E_G - E_A}{3mc^2}}$$



Cathode Surface Roughness

Emittance Growth Due to Non-Uniform Emission & Field Enhancement -Highest cathode field not necessary best emittance-



Length (microns)

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Emittance Growth Due to Field Enhancement

The Brightest Beam Possible* - How much can the LCLS gun emittance be lowered? -

Assume all linear and non-linear space charge effects can be corrected/compensated for, assume the cathode is perfectly flat and the cathode physics is correct. Then the lower limit on the emittance depends on the thermal emittance for the divergence and the space charge limit for the beam size:

$$\mathcal{E}_{smallest} = \sigma_{x,SCL}(E_{cathode}) \times \frac{\mathcal{E}_{thermal}}{\sigma_{x}} (microns / mm - rms)$$

$$\frac{\mathcal{E}_{thermal}}{\sigma_{x}} = \sqrt{\frac{\hbar\omega - \phi_{eff}}{3mc^{2}}}$$

$$E_{cathode} = \frac{\sigma_{surface charge density}}{\varepsilon_{0}} = \frac{Q_{bunch}}{\pi R_{cathode}^{2}}$$

$$\sigma_{x,SCL} = \sqrt{\frac{Q_{bunch}}{4\pi\varepsilon_{0}E_{cathode}}}$$

$$\mathcal{E}_{smallest} = \sqrt{\frac{Q_{bunch}}{12\pi\varepsilon_{0}E_{cathode}}} \sqrt{\frac{Q_{bunch}}{12\pi\varepsilon_{0}E_{cathode}}}} \sqrt{\frac{Q_{bunch}}{12\pi\varepsilon_{0}E_{cathode}}} \sqrt{\frac{Q_{bunch}}{12\pi\varepsilon_{0}E_{cathode}}}} \sqrt{\frac{Q_{bunch}}{12\pi\varepsilon_{0}E_{cathode}}} \sqrt{\frac{Q_{bunch}}{12\pi\varepsilon_{0}E_{cathode}}}} \sqrt{\frac{Q_{bunch}}{12\pi\varepsilon_{0}E_{cathode}}} \sqrt{\frac{Q_{bunch}}{12\pi\varepsilon_{0}E_{cathode}}}} \sqrt{\frac{Q_{bunch}}{12\pi\varepsilon_{0}E_{cathode}}} \sqrt{\frac{Q_{bunch}}{12\pi\varepsilon_{0}E_{cathode}}}} \sqrt{\frac{Q_{bunch}}{12\pi\varepsilon_{0}E_{cathode}}}} \sqrt{\frac{Q_{bunch}}{12\pi\varepsilon_{0}E_{cathode}}}} \sqrt{\frac{Q_{bunch}}{12\pi\varepsilon_{0}E_{cathode}}}} \sqrt{\frac{Q_{bunch}}{12\pi\varepsilon_{0}E_{cathode}}}} \sqrt{\frac{Q_{bunch}}{12\pi\varepsilon_{0}E_{cathode}}}} \sqrt{\frac{Q_{bunch}}{12\pi\varepsilon_{0}E_{cathode}}}} \sqrt{\frac{Q_{bunch}}{12\pi\varepsilon_{0}E_{cathod}}}} \sqrt{\frac{Q_{bunch}}{12\pi\varepsilon_{0}E_{cathod}}}} \sqrt{\frac{Q_{bunch}}{12\pi\varepsilon_{0}E_{ca$$

Е

*Foi

Model for Space Charge Emittance due to Emission Non-Uniformities



Space Charge Emittance Near the Cathode

100%

$$\Delta \varepsilon_{n,sc} = \sigma_x \frac{2r_0}{\pi R} \sqrt{\frac{eQ \ln a}{\varepsilon_0 mc^2 l_b}}$$
 emittance for
100% modulation
In terms of the peak current: $I = \frac{Qc}{L}$

ec $=\frac{cc}{m}\approx 17kA$ and the characteristic current: I_0 r

$$\Delta \varepsilon_{n,sc} = \sigma_x \frac{2r_0}{\pi R} \sqrt{\frac{I}{I_0} \ln a}$$

The spatial frequency (modulations/radius), in terms of the overall laser radius, R, and modulation spacing or period, $4r_o$, is

$$f_s = \frac{R}{4r_o}$$

Which gives the emittance due to space charge expansion of the initial modulation with spatial frequency f_s :

$$\Delta \varepsilon_{n,sc} = \sigma_x \frac{1}{2\pi f_s} \sqrt{\frac{I}{I_o} \ln a}$$

0.6 0.4 0.2 (mm) v.0 -0.2 -0.4 -0.6 0.2 0.4 \times (mm)



RF Emittance Contribution

RF emittance given by Kim:

$$f = \frac{eE_0}{2mc^2} \frac{\sigma_x \sigma_\phi}{\sqrt{2}}$$

1 nC $\sigma_z = 1.10 \text{ mm rms}$ $\sigma_{\phi} = 0.064 \text{ rad rms}$ $\varepsilon_{rf} = 0.326 \text{ microns}$





0.25 nC $\sigma_z = 0.74 \text{ mm rms}$ $\sigma_{\phi} = 0.043 \text{ rad rms}$ $\varepsilon_{rf} = 0.15 \text{ microns}$

 \mathcal{E}_{n}





 $E_0 = 115MV/m$ $\sigma_x = 1mm$ 0.020 nC $\sigma_z = 0.21 \text{ mm rms}$ $\sigma_{\phi} = 0.012 \text{ rad rms}$ $\varepsilon_{rf} = 0.011 \text{ microns}$





⁻¹ Slide compliments P. Emma

Optical Aberrations: Chromatic Effects of the Solenoid

$$\varepsilon_{n,chromatic} = \beta \gamma \sigma_x^2 \sigma_p \left| \frac{d}{dp} \left(\frac{1}{f_{sol}} \right) \right| \qquad \frac{1}{f_{sol}} = K \sin KL, \quad \mathbf{K} = \frac{\mathbf{B}(0)}{2\mathbf{B}\rho_0}$$

$$\varepsilon_{n,chromatic} = \beta \gamma \sigma_x^2 K (\sin KL + KL \cos KL) \frac{\sigma_p}{p}$$



Assumes 1 mm rms beam size at solenoid



Solenoid chromatic aberration is a significant contributor to the projected emittance. For a slice energy spread of 1 KeV, gives ~0.02 microns

Quadrupole Field Error of Gun Solenoid

Normal and Skew quad correctors were installed to compensate small quad fields at ends of gun solenoid



Relatively strong effect on the beam emittance, especially at high charge.







Correlation Plot 28-Apr-2010 19:43:55



Aberration of Gun Solenoid with "Perfect" Axial Field

Transverse distributions near the focus after Solenoid

Begin with a uniform, square distribution having zero emittance and zero energy spread

time=2.401e-009 time=2.3995e-009 time=1e-012 4e-4 0.004 2e-4 0.002 y(mm) y(mm) y(mm) 0e-4 0.000 -2e-4 -0.002 -4e-4 -0.004 -0.005 0.000 0.005 -5e-4 0e-4 5e-4 2 GPT x(mm)E GPT x(mm) x(mm) Emittance vs. z 100 Solenoid Bz vs. z "Perfect" solenoid has a small "pincushion" distortion. 10 + 2.5

Initial transverse distribution

2.0

1.0

0.5

0.0

GPT

0.0

0.2

0.4

avgz(m)

0.6

0.8

avgfBz(KG) 1.5



Conference^{0.8}

1.0

H. Dowell -- 2014

A 4 mm x 4 mm(FW) object gives 0.01 micron emittance. Nominal beam is 1mm(rms) or 2 mm x 2 mm(FW) results in only 0.0025 microns.

Gun Solenoid with Quadrupole Field Errors



Correcting Field Errors with Quad Correctors



Quad corrector field maps



Normal and skew quad correctors installed along the full length of the solenoid to compensate for the solenoid's end quad fields. These long quad correctors are very effective at canceling the emittance of the much shorter quad error fields.



What are the Quad Correctors correcting?



The skewed quad fields produce emittance growth due to coupling of the x- and yplanes (see Paul's talk), and the quad correctors remove this skew:

$$\Delta \bar{\varepsilon}_{x} \approx \varepsilon_{x0} \frac{\beta_{x0} \beta_{y0}}{2f^{2}} \left(\frac{\varepsilon_{y0}}{\varepsilon_{x0}}\right) \sin^{2}(2\varphi)$$

Compared to a usual quad skew angle of <1 deg. In this case the skew angle can be 10's of degrees and is determined by the rotation of it's initial direction in the axial field.

The orientation of the total quad field is the vector sum of the entrance quad vector rotated by the solenoid plus the exit quad vector:



Summary and Conclusions

Cathode Intrinsic Emittance

•Self-consistent analysis of QE and emittance data indicate the theoretical emittance is factor of ~2 lower than expt.

•Cathode surface roughness important at high cathode fields. Less than 20 nm peak-to-peak required for sub-0.1 micron emittance.

•Lowest possible emittance given space charge limit of smallest possible size on cathode and divergence due to intrinsic emittance.

•Transverse uniformity of laser + QE.

•Transverse non-uniformity drives the emittance during acceleration from rest to c.

•High spatial frequencies (>~50 periods/radius) are small contributors to the emittance

•RF emittance increases with charge due to longitudinal space charge

•Small for LCLS at 20 pC, ~ 0.01 microns

Solenoid optical effects seem to be the most important (after the cathode)

•Emittance due to chromatic aberration

•@250pC the projected energy spread is 20 KeV => ~0.3 microns

•For a slice energy spread of 1 KeV => ~0.03 microns

•Emittance growth due to geometric aberrations appear to be small.

•Spherical and pincushion distortion contribute if beam is larger than 2 mm (FW)

•Coupling to space charge effects still need to be analyzed

Solenoid field errors are important

•Skewed quadrupole field errors strongly affect emittance

•Although field errors are at ends of solenoid, long quad correctors are effective at canceling growth

Everything is Important Below 0.1 microns!!



Thanks to my colleagues at both SLAC and LBNL

